



정확한 다이내믹 전류 및 노이즈 측정

전류 측정 원리부터 IsoVu™ 절연 전류프로브 실제 활용 사례까지





Agenda

- Basics of Current Measurement
- Current measurement on an oscilloscope
 - Base on a sensor
 - Base on Ohm's Law
- Bandwidth of Current Probes and Limitations
- Introducing: TICP Series IsoVu Isolated Current Probe
- Shunt Resistance and Measurement Range
- Uses Cases
 - High Power
 - Low Power



What is current?

DEFINITION AND COMMANALOGIES

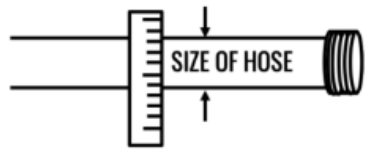
Voltage

Volts (V)



Current

Amps (A or I)

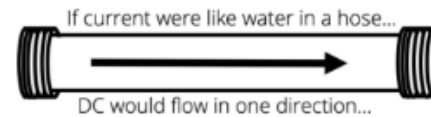


Resistance

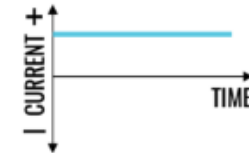
Ohms (R or Ω)



DC

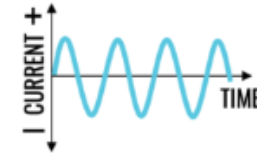


FREEING
ENERGY



Things that use DC

AC



Things that use AC

Source: freeingenergy.com



Why do we measure current?

$$P = V \times I$$

Power Electronics characterization,

Electric energy **consumption**, converters efficiency determination

Monitor load absorption,

Implement current based feedback control

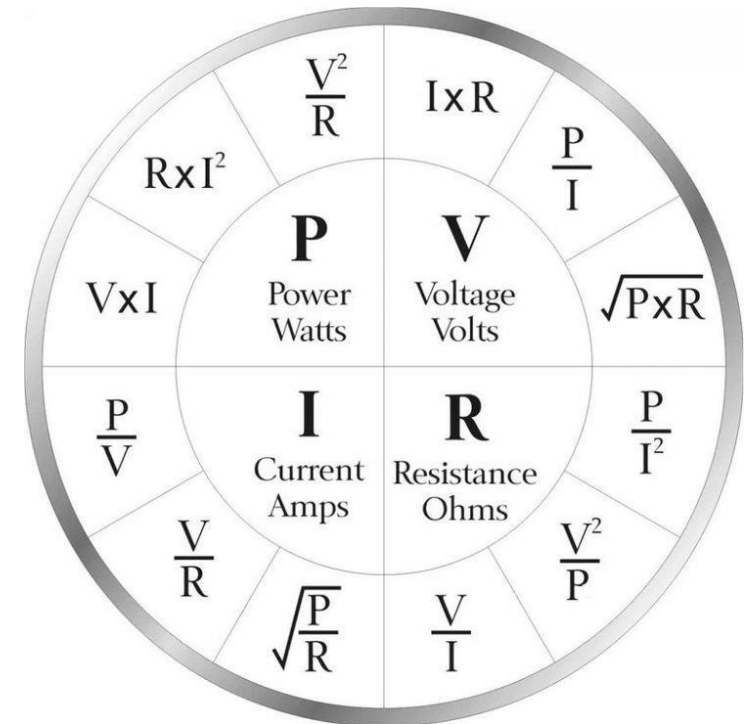
Calculate **battery duration,**

storage discharge time...

Insulator resistance measurements

Detection of shorts, over currents, diagnose malfunctioning...

Other...



How do we measure current?

NOMENCLATURE AND SEMANTIC

How= using **what** equipment+ using **which** technique

It depends on the Application Context

nA DC not the same as kA AC

Measure vs Sense

Examples:

SMU

DMM

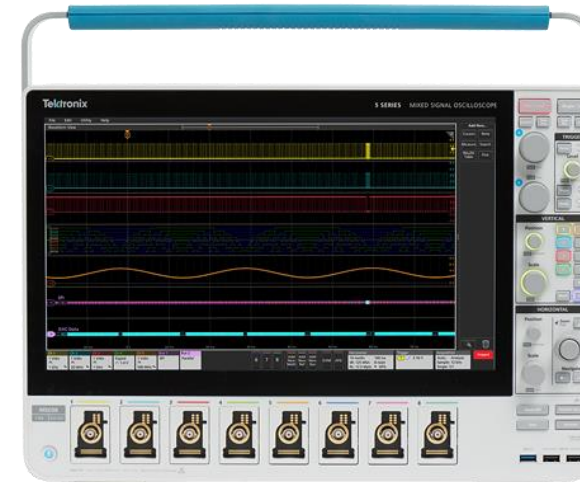
Oscilloscope



SMU



DMM

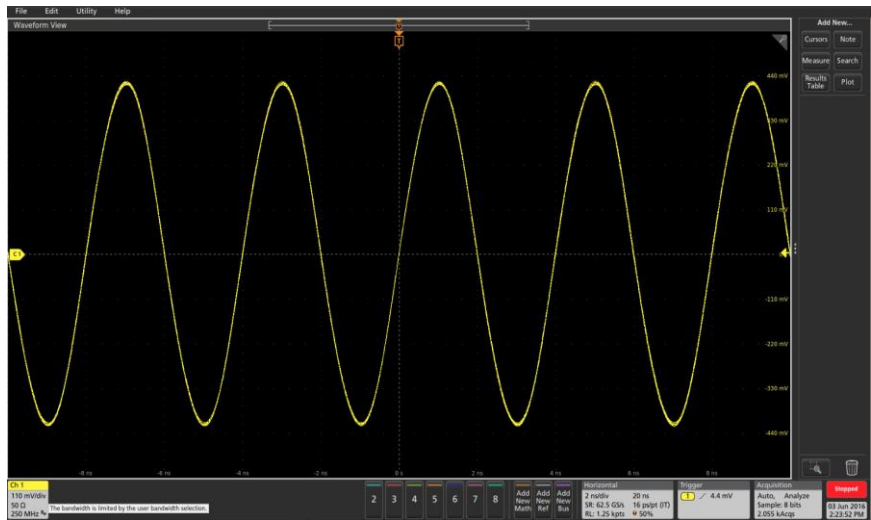


Oscilloscope



Can Oscilloscopes measure current?

Voltage \updownarrow



Time \rightarrow

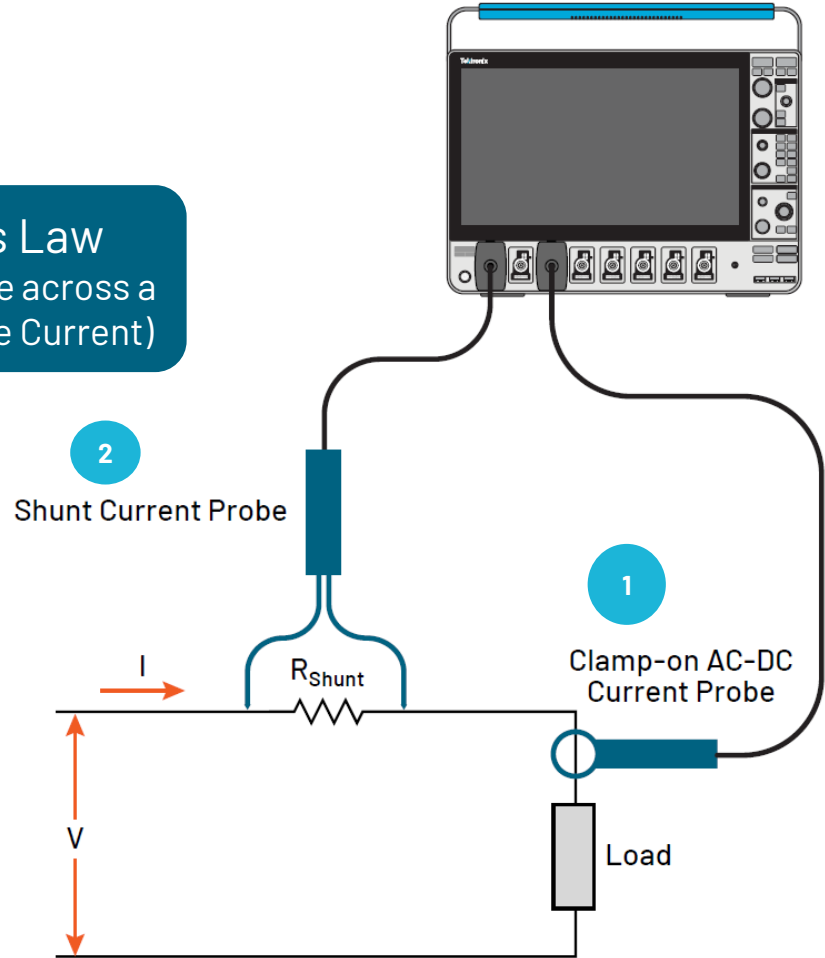


Yes, But need to get it converted into Voltage



Two Main Current Probing Techniques

2 Based on Ohm's Law
($V = IR$; Measure Voltage across a known shunt and derive Current)



1 Based on a sensor
(Hall sensor, Rogowski coils)
Simple. and most popular



Based on a sensor

AC CURRENT PROBE

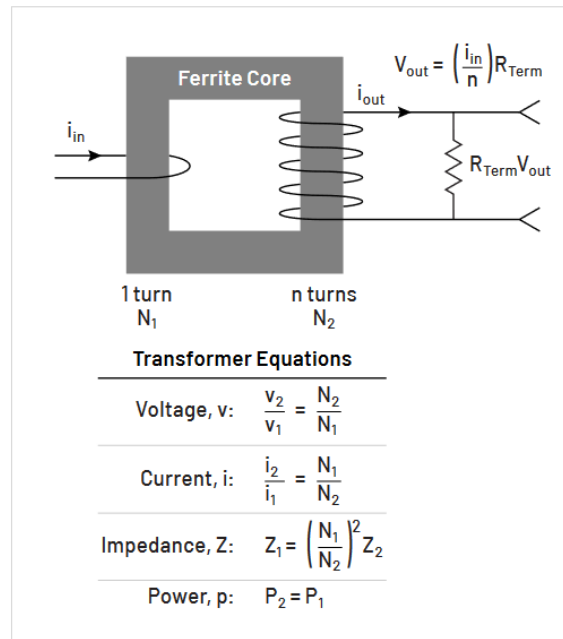
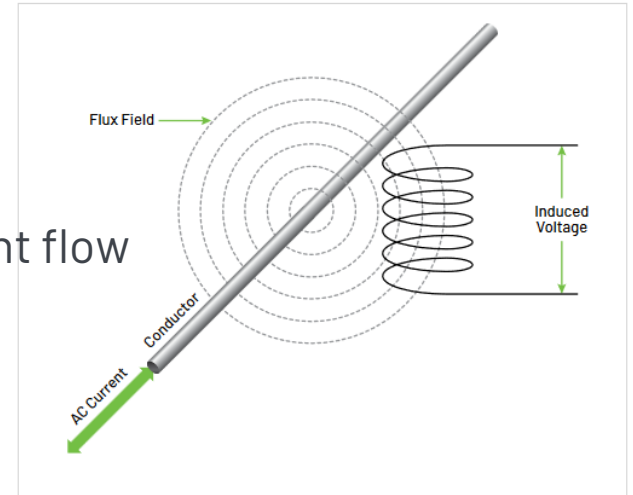
Measures the electromagnetic flux field around conductor to determine the current flow

Types:

- AC current probes (passive)

Features to Consider:

- High current measurement
- Small footprint
- Low Bandwidth
- Manual scaling and units



Tektronix TRCP3000
AC Current Probe
3000 A, 1Hz to 16 MHz

Based on a sensor

AC/DC CURRENT PROBE

Measures the electromagnetic flux field around conductor to determine the current flow

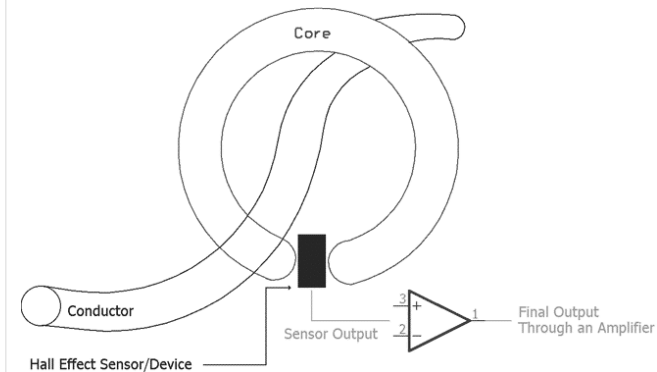
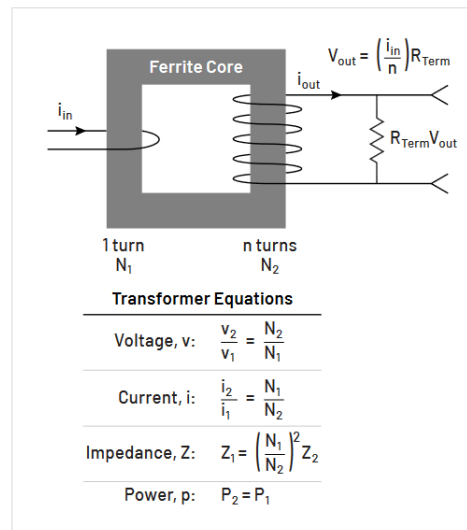
Added Hall sensor for DC current measurement

Types:

- AC/DC current probes (active)

Features to Consider:

- Operating power supply
- Automatic scaling and units



Tektronix TCP0150
AC/DC Current Probe
150 A, DC to 20 MHz

Based on Ohm's Law

Using Ohm's Law:

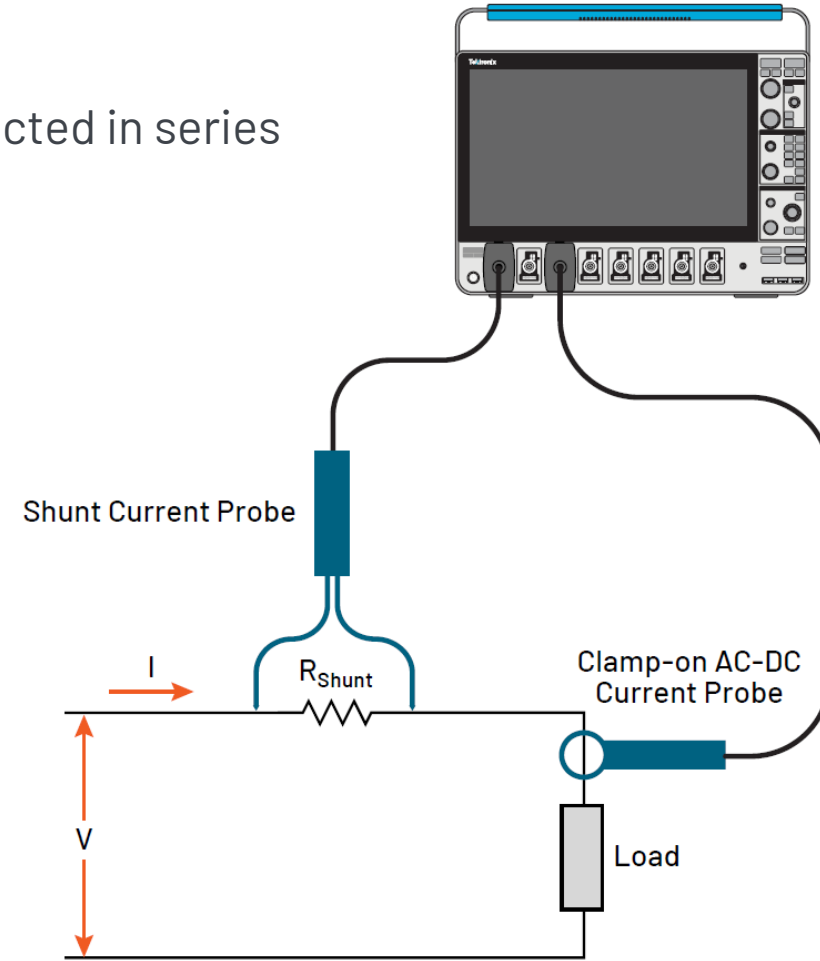
- measuring the voltage across a known resistance connected in series

Ohm's Law:

$$I = \frac{V}{R}$$

Features to Consider:

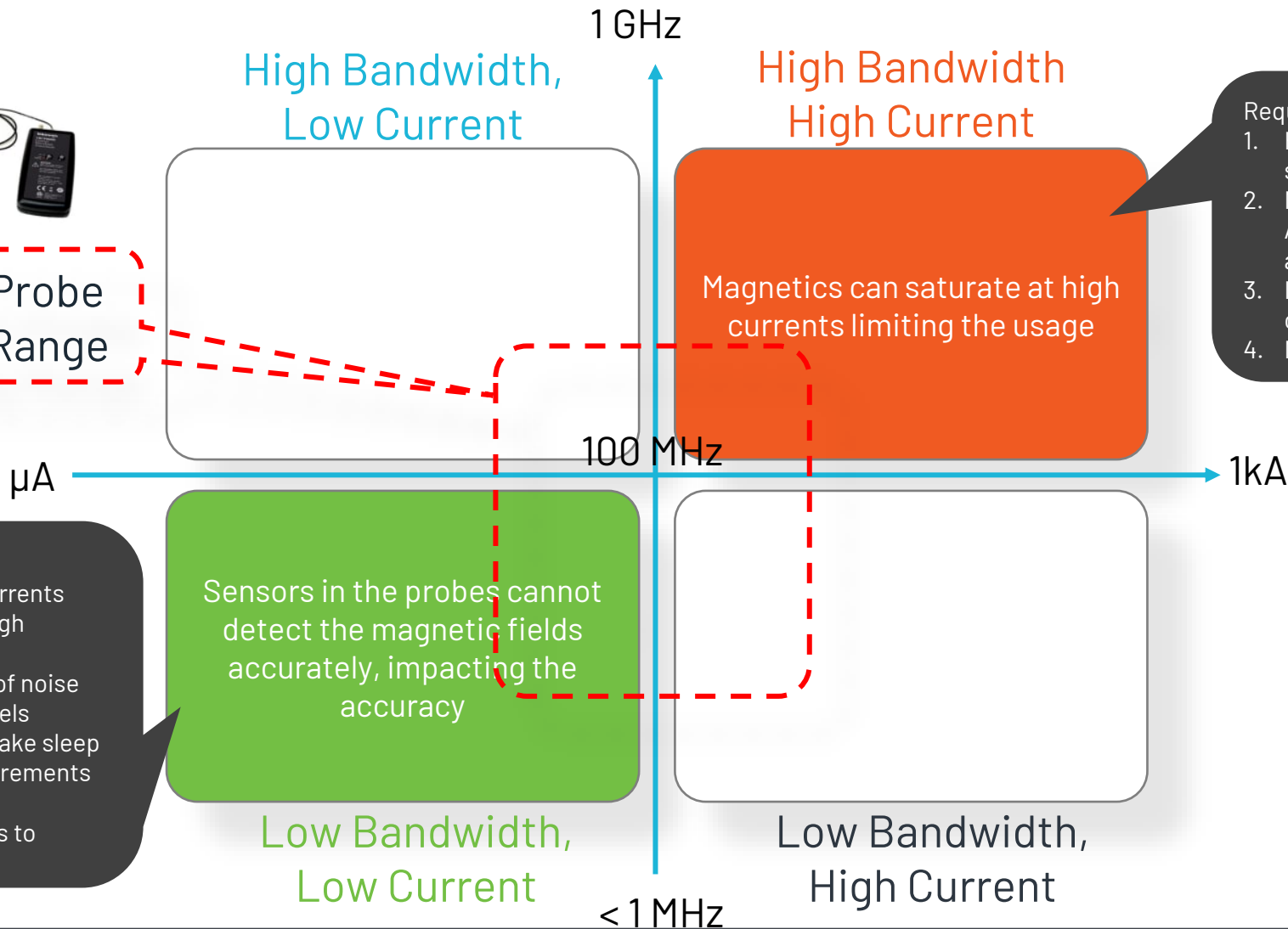
- Resistance values
- Tolerance
- Temperature coefficient
- Power rating



New Segments Emerging



Clamp-on Probe Operating Range



- Requirements:
1. High Bandwidth to measure fast switching transients
 2. Measure high currents driven by Automotive and Industrial applications
 3. Isolation for rejecting the impact of common mode transients (CMRR)
 4. Measure High Currents with Safety



- Requirements:
1. Measure μA to mA low-currents with high accuracy and high sensitivity
 2. Low noise - as presence of noise impacts results at low levels
 3. Wide dynamic range to make sleep and active current measurements with a single probe tip
 4. Connectivity - flexible tips to connect to tight spaces

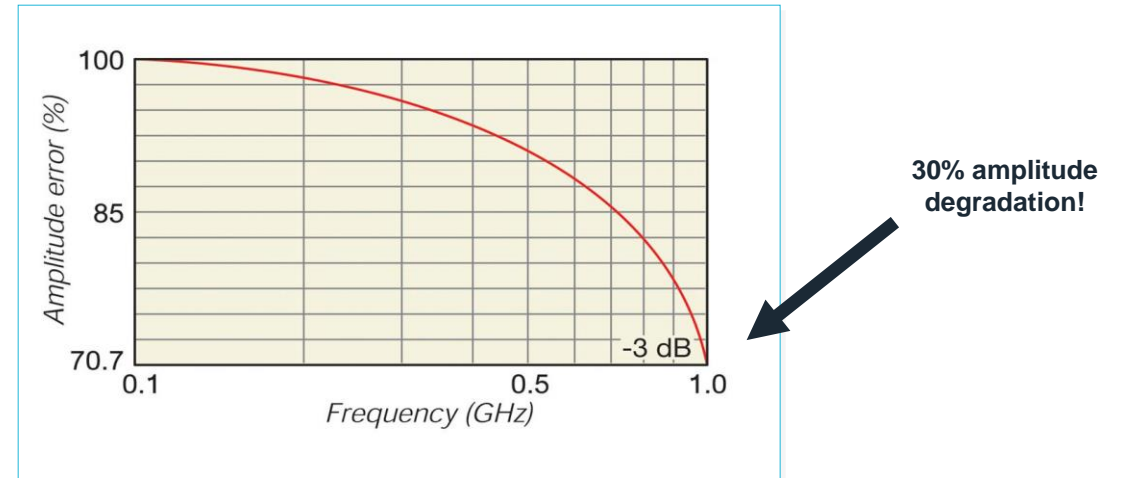


Bandwidth

Must have sufficient bandwidth to capture high frequency components

Bandwidth specified at -3 dB point

$$BW = \frac{0.35}{t_{\text{rise}}} \quad t_{\text{rise}} = \frac{0.35}{BW}$$

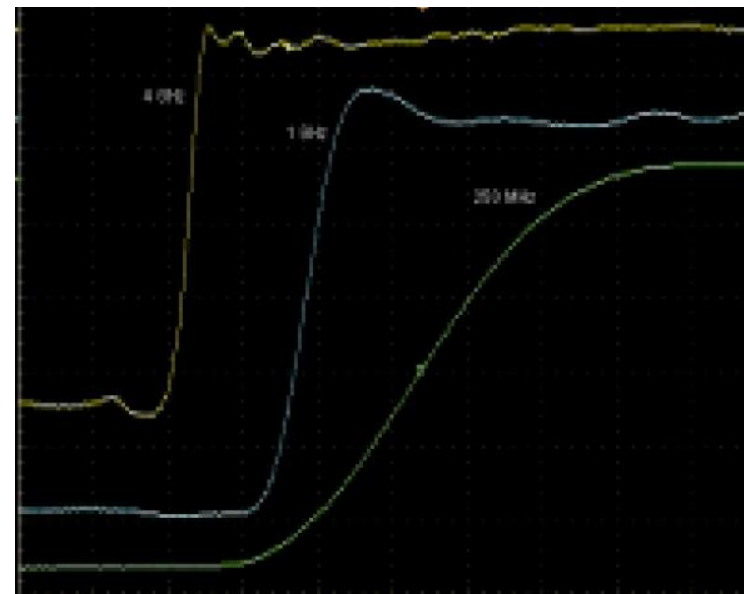
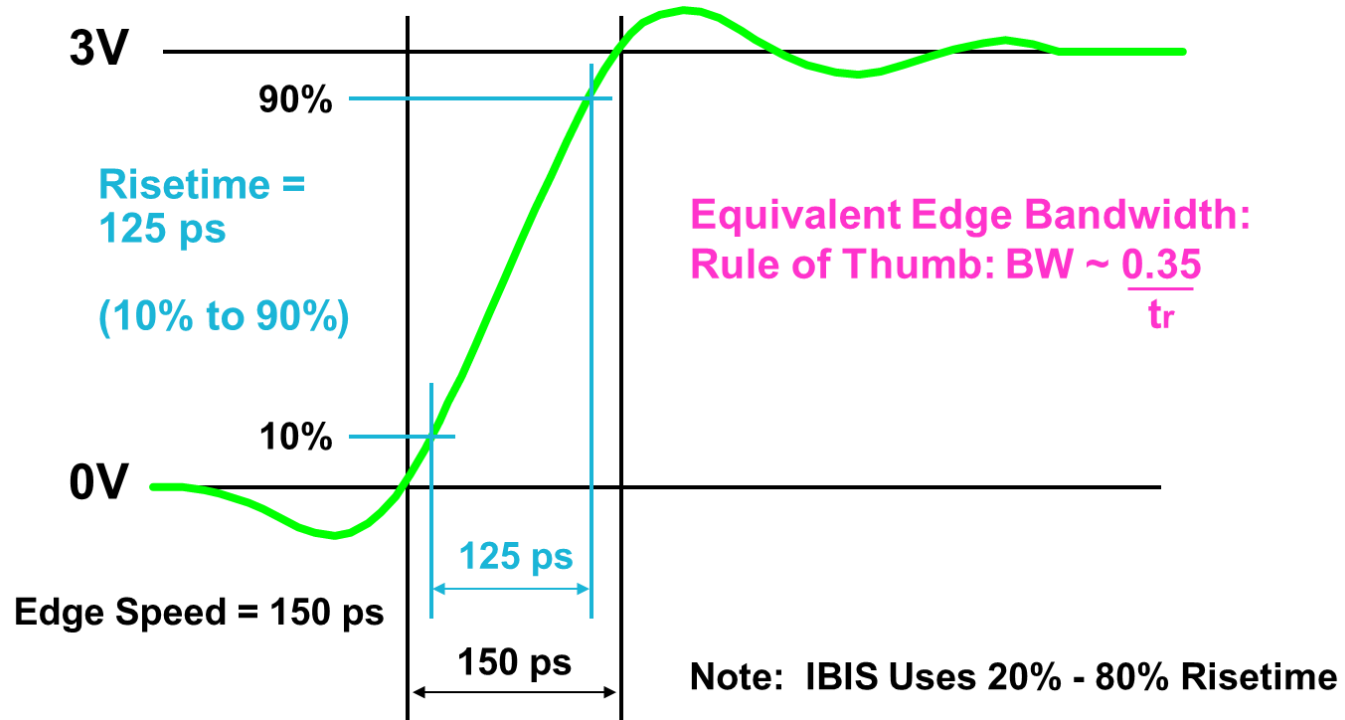


At the 3dB bandwidth frequency, the vertical amplitude error will be approximately 30%.

When you depend on the specified maximum vertical amplitude error, divide the specified bandwidth by 3 to 5 as a rule of thumb, unless otherwise stated.

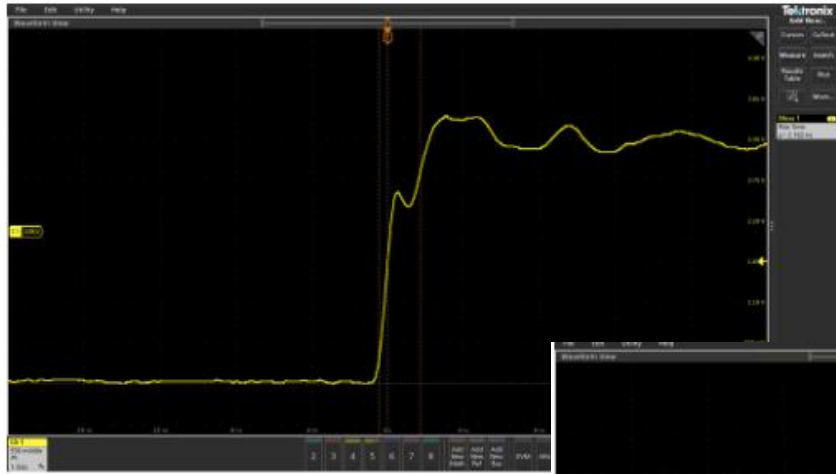


Rise Time

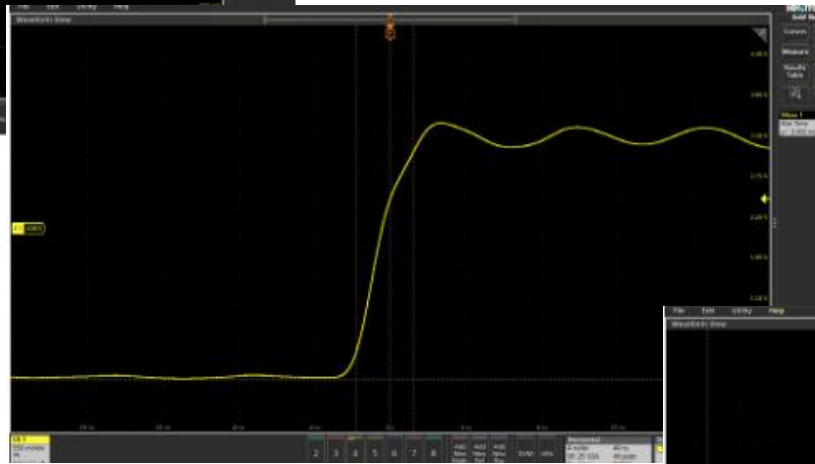




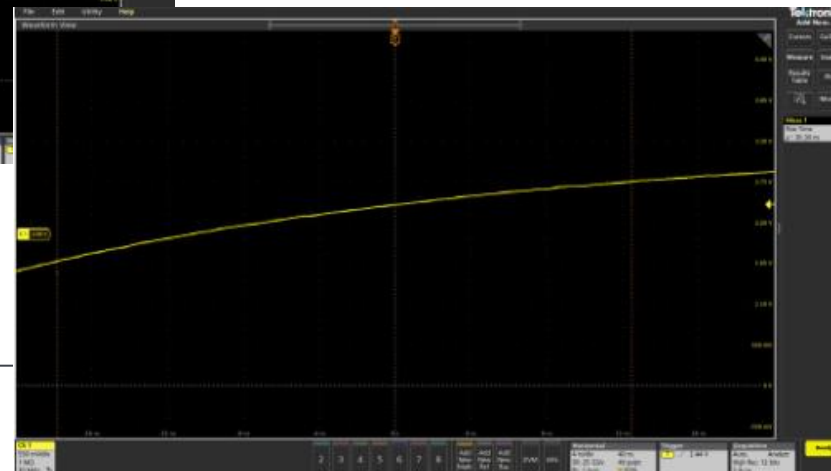
Relationship Between Bandwidth & Rise Time



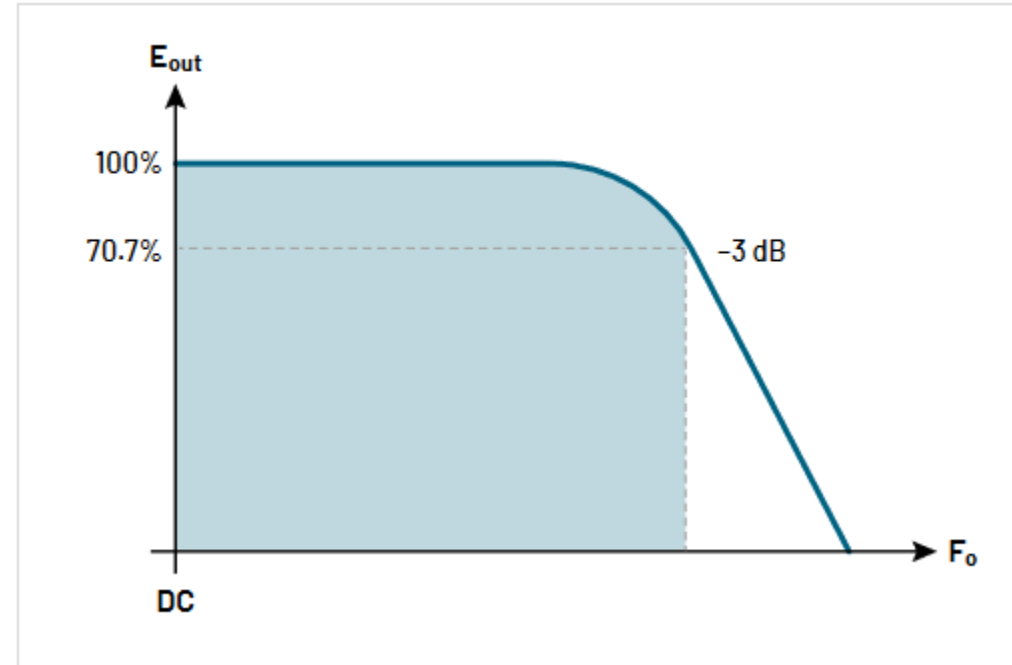
1GHz Probe



200MHz Probe



20MHz Probe





What's pushing the High Bandwidth and Current needs?

Automotive:

- Battery Technology Advancements
 - Smaller batteries with higher efficiency
- Demand for Performance, Faster Charging and Range Improvements
 - More power - Higher voltage/current levels = More distance traveled, faster recharge cycles
- Emergence of New Market Segments
 - Heavy duty vehicles – Trucks, Buses, Off-roading vehicles



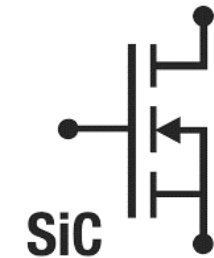
Industrial:

- Efficient Turbines and Advancements in Solar Power
 - Generate significantly higher power outputs



Power Semi:

- Adoption of WBG Technology
 - Switching frequency rising due to WBG device validation





Summarizing the Requirements...

A Current probe that meets...



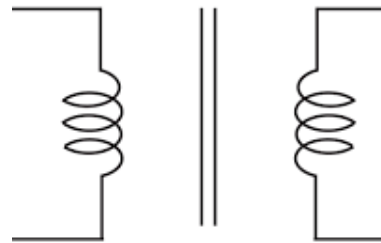
High Bandwidth

View transient signals



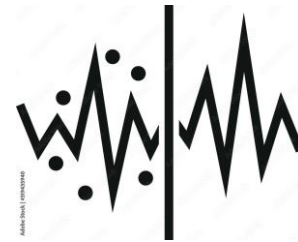
High Sensitivity

Reduce noise amplification



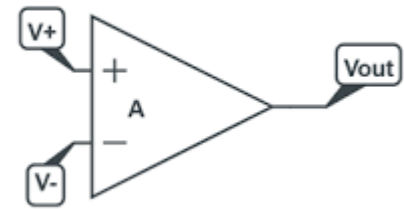
Isolation

Reduce ground loop and bounce



Low Noise

Measure signals in μA



High CMRR

Reject common signals for better resolution

And purpose built for making current shunt measurements



Introducing: TICP Series IsoVu™ Isolated Current Probes

INDUSTRY FIRST RF ISOLATED CURRENT PROBES

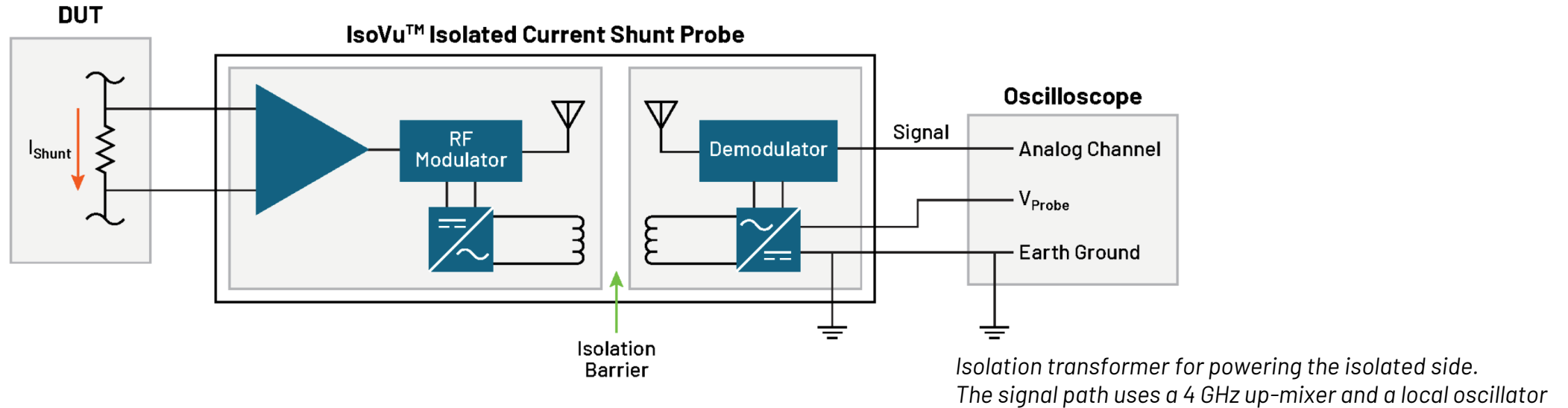


Bandwidth	250 MHz, 500 MHz, 1 GHz
DC Gain Accuracy	± 1.5%
Isolation	RF Isolation scheme
Common Mode Rejection Ratio (CMRR)	140 dB at DC Up to 90 dB at 1 MHz
Common Mode Voltage	1800 V; For use in a Pollution degree 1 environment 1300 V; Pollution degree 2 1000 V CAT II; 600V CAT III
RMS Input Referred Noise	4.7 nV/RT Hz (<150 µV at 1 GHz, <21 µV at 20 MHz)
Current Measurements	AC + DC
Compatible Oscilloscopes	4 Series MSO, 5 Series MSO, 6 Series MSO, 4 Series B MSO, 5 Series B MSO, 6 Series B MSO, 5 Series MSO LP



Active Isolated Current Shunt Probe

INDUSTRY FIRST RF ISOLATED CURRENT PROBES



Advantages of Electrical Isolation in Current Measurements:

- Enables safety and accuracy (due to improved common mode rejection)
- Low-noise architecture offers greater sensitivity than a standard differential probe
- Lower Burden Voltage: Decreases loading on DUT
- Increases usable bandwidth
- Increased common mode range (90dB at 1 MHz)



What's in the standard package?



Probe Tip Specifications



Probe Tips	1X SMA Input	1X MMCX Tip	10X MMCX Tip	100X MMCX Tip
Main Purpose	Lowest-noise	Lowest-noise	Debug	High-side Vgs
Dynamic Range and Max Voltage	±0.5V	±0.5V	±5V	±50V
Maximum Non-Destructive Differential Voltage	1V RMS	1V RMS	5V pk	50V pk
Input Resistance	50 Ω	50 Ω	500Ω	5000Ω
Capacitance	-	-	<3pF	<3pF
Length	0.025M (1")	0.15M (6")	0.15M (6")	0.15M (6")
Noise Floor	<21 μV _{RMS} at 20 MHz	<21 μV _{RMS} at 20 MHz	<210 μV _{RMS} at 20 MHz	<2.1 mV _{RMS} at 20 MHz

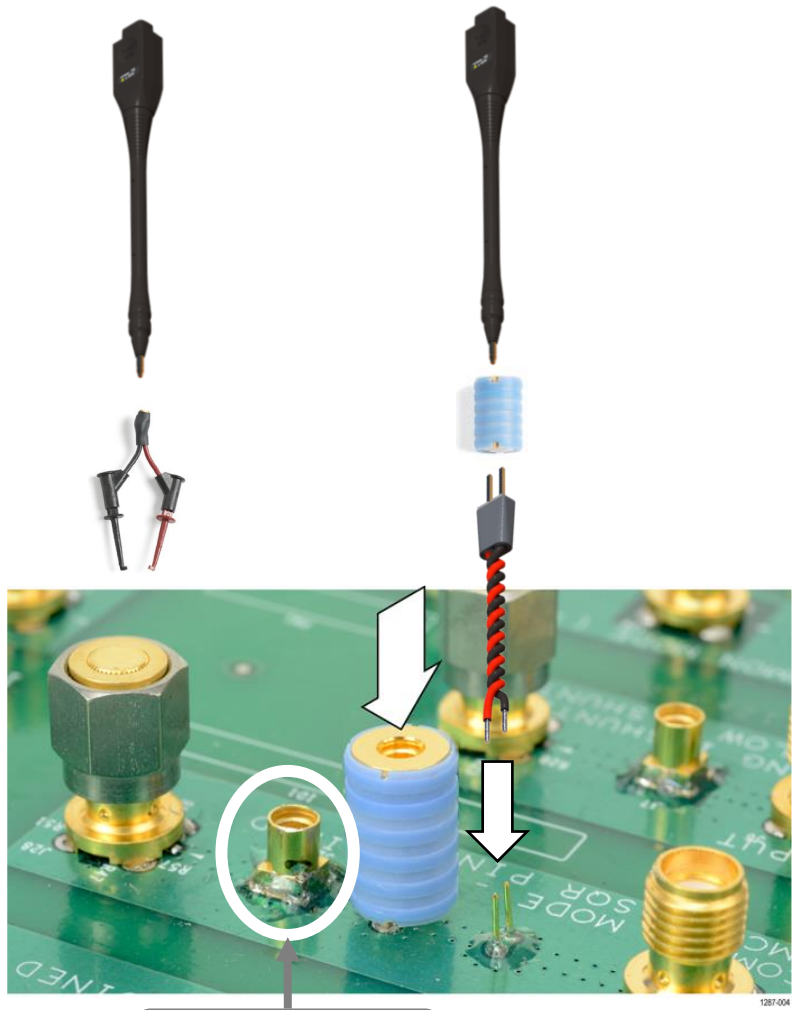


How to connect to off the shelf shunts?

CONNECTION EXAMPLES



MMCX to sq pin adapter



MMCX Connector



Coaxial shunts + SMA Adapter

Coaxial shunts + MMCX Adapter

TICP Accessory Options



MMCX to IC
Grabber



Square pin to IC
Grabber



Square Pin Y-Lead



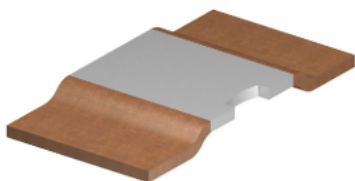
MicroCKT Grabber

Popular Types of Shunts

EXAMPLES

Vishay

Power Metal Strip® Resistors, Very High Power (to 15 W), Low Value (Down to 0.0001 Ω), Surface-Mount



FEATURES

- All welded construction of the Power Metal Strip® resistors are ideal for all types of current sensing, voltage division and pulse applications
- Proprietary processing technique produces extremely low resistance values, down to 0.0001 Ω
- Sulfur resistance by construction that is unaffected by high sulfur environments
- Specially selected and stabilized materials allow for high power rating (to 15 W)
- Very low inductance 0.5 nH to 5 nH
- Low thermal EMF (< 3 μV/°C)
- AEC-Q200 qualified ⁽¹⁾
- Material categorization: for definitions of compliance please see www.vishay.com/doc299912



Note

⁽¹⁾ Flame retardance test may not be applicable to some resistor technologies

T&M Research (CVR)

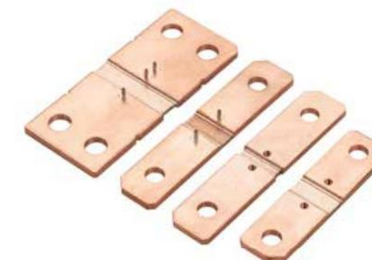


SHA Series

Precision manganin copper alloy shunt

The Ohmite SHA series shunts can support up to 1KA of rated current. Due to its special alloy material, the SHA series has good long-term stability and can withstand pulse current several times higher than the rated current. The special heat treatment process of the SHA series enables a low current coefficient providing stability in high current applications. The SHA series has thermal potential of less than 0.5pV/°C to copper, and has little effect on the voltage output of the millivolt level. The flat structure of the SHA series makes the inductance less than 3nH creating a shunt compatible with high frequency applications.

Ohmite

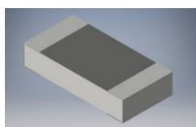


Bourns

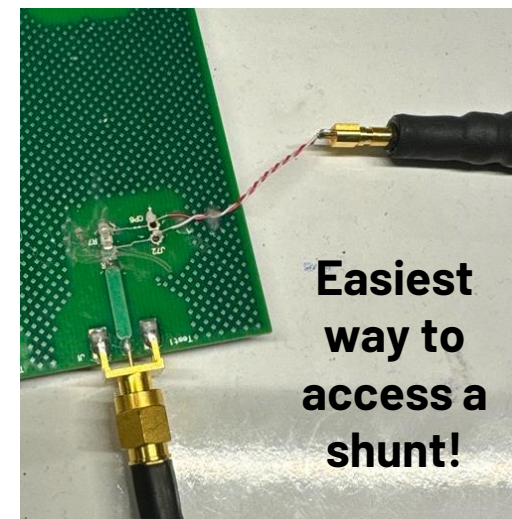


Stackpole

Stackpole Electronics, Inc.
Resistive Product Solutions



PMK, Uni of Cambridge



Easiest way to access a shunt!

The TICP works with any off the shelf shunts as long as we have access, and the voltage drop <0.5V with 1X tip



Min and Max Currents

- Min currents are dependent on the noise floor
 - $I_{\min(\text{rms})} = V_{\min} / R_{\text{shunt}} = [4.7 \text{ nV} / \sqrt{\text{Hz}} \times \sqrt{(\text{Bandwidth})}] / (R_{\text{shunt}})$
- Max current depends on shunt power rating
 - $I_{\max(\text{rms})} = (\text{Max input } V_{\text{pk}}) / R_{\text{shunt}}$

4. Gain Settings

Gain settings help understand the tradeoffs between noise, sensitivity and dynamic range

Probe Ranges

Numbers are published for TICPSMA and TICPMM1 tips. For 10X or 100X tips, multiply by 10 or 100 respectively.

Input range	Offset range	RMS noise spectral density (V_{RMS})	Noise floor at 20 MHz (V_{RMS})
±0.5 V	±0.15 V	22.9 nV / $\sqrt{\text{Hz}}$	102.5 μV_{RMS}
±0.35 V	±0.30 V	17.4 nV / $\sqrt{\text{Hz}}$	77.8 μV_{RMS}
±0.25 V	±0.40 V	15.0 nV / $\sqrt{\text{Hz}}$	67.2 μV_{RMS}
±0.175 V	±0.475 V	9.5 nV / $\sqrt{\text{Hz}}$	42.4 μV_{RMS}
±0.125 V	±0.5 V	8.7 nV / $\sqrt{\text{Hz}}$	38.9 μV_{RMS}
±0.09 V	±0.5 V	6.3 nV / $\sqrt{\text{Hz}}$	28.3 μV_{RMS}
±0.065 V	±0.5 V	5.5 nV / $\sqrt{\text{Hz}}$	24.7 μV_{RMS}
±0.045 V	±0.5 V	4.7 nV / $\sqrt{\text{Hz}}$	21.2 μV_{RMS}
±0.03 V	±0.5 V	4.7 nV / $\sqrt{\text{Hz}}$	21.2 μV_{RMS}
±0.02 V	±0.5 V	4.7 nV / $\sqrt{\text{Hz}}$	21.2 μV_{RMS}

1. Min currents table

Shunt selection	20 MHz	250 MHz	1 GHz
50 Ω TICP as shunt	420 nA	1.5 μA	3.0 μA
5 Ω shunt	4.2 μA	14.9 μA	29.7 μA
1 Ω shunt	21 μA	74.3 μA	149 μA
500 m Ω shunt	42 μA	149 μA	297 μA
50 m Ω shunt	420 μA	1.5 mA	3.0 mA
5 m Ω shunt	4.2 mA	14.9 mA	29.7 mA
500 $\mu\Omega$ shunt	42 mA	149 mA	297 mA
50 $\mu\Omega$ shunt	420 mA	1.5 A	3.0 A
15 $\mu\Omega$ shunt	1.4 A	5.0 A	9.9 A

2. Max currents table

Shunt selection	TICPMM1	TICPSMA	TICPMM10	TICPMM100
50 Ω TICP as shunt	13 mA		-	-
5 Ω shunt	130 mA		1.3 A	10 A
1 Ω shunt	650 mA		6.5 A	50 A
500 m Ω shunt	1.3 A		13 A	100 A
50 m Ω shunt	13 A		130 A	1.0 kA
5 m Ω shunt	130 A		1.3 kA	10 kA
500 $\mu\Omega$ shunt	1.3 kA		13 kA	100 kA
50 $\mu\Omega$ shunt	13 kA		130 kA	1000 kA
15 $\mu\Omega$ shunt	43.3 kA		433.3 kA	3300 kA

3. Input Voltage Range

Ensure the tip voltages do not exceed max value

Probe tips	Differential input voltage range	Offset range	Maximum measurable input voltage (Vpk)	Maximum non-destructive differential voltage	Input impedance
TICPSMA	±0.5 V	±0.5 V	0.65 V	±3 V; 3 V_{RMS}	50 Ω N.A.
TICPMM1	±0.5 V	±0.5 V	0.65 V	±3 V; 3 V_{RMS}	50 Ω N.A.
TICPMM10	±5 V	±5 V	6.5 V	±15 V; 15 V_{RMS}	500 Ω <3 pF
TICPMM100	±50 V	±50 V	50 V	±60 V; 50 V_{RMS}	5000 Ω <3 pF

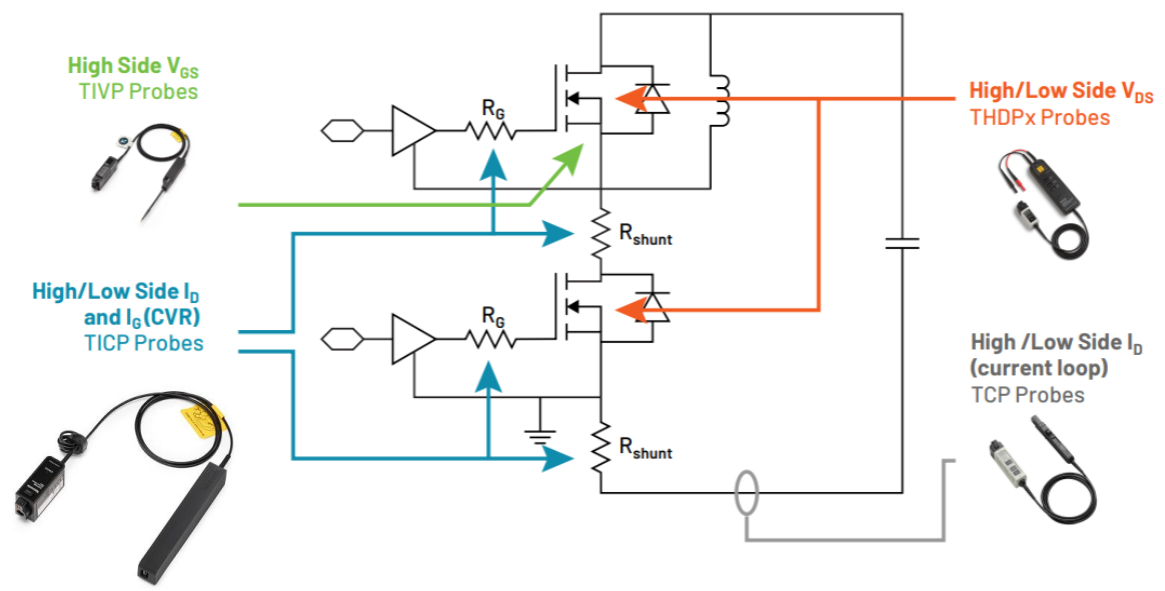
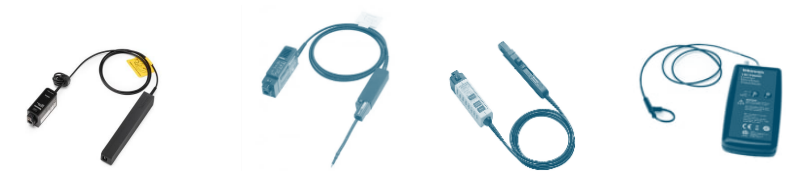
High Power Example Uses Cases





How does TICP compare to other probes?

HIGH-POWER



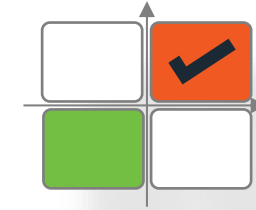
Market Solutions	TICP with Shunt	IsoVu / TIVP with Shunt	TCPx Current Probes	Rogowski Current Probes
Bandwidth	High	High	Medium	Low
DC Coupling	Yes	Yes	Yes	None
Isolation	Yes	Yes	Yes	Yes
Intrusive	Yes	Yes	No	No
Common Mode Voltage	1.8kV	60kV	N/A	N/A
Position	Doesn't matter	Doesn't matter	Important	Important
Saturation	No	No	Yes	No
Probe Tip size	Small	Small	Large	Large
CMRR	Medium	High	N/A	N/A



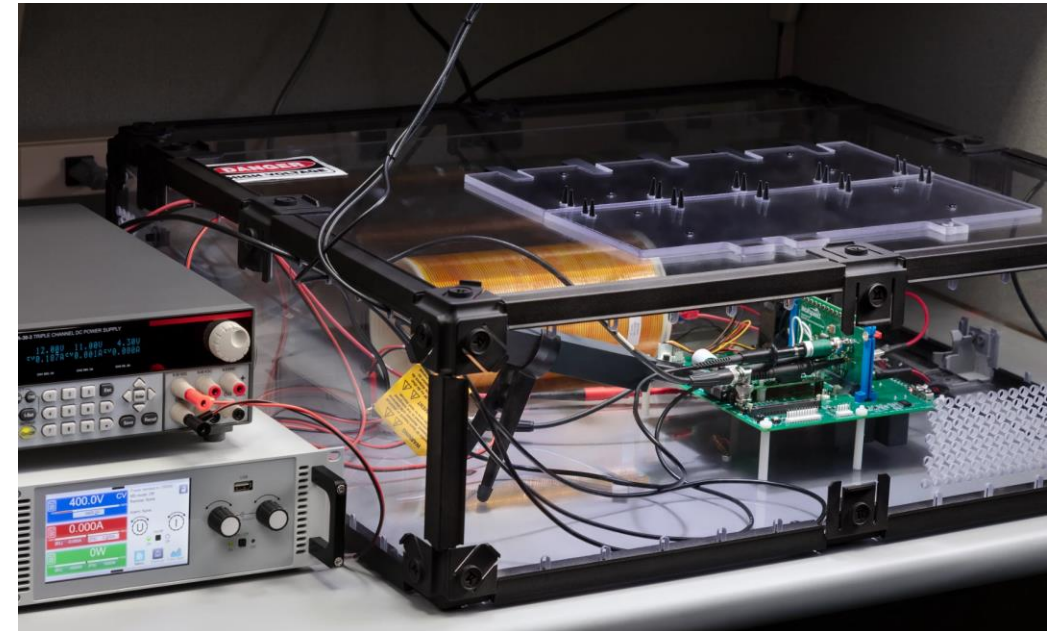
Ideal for SiC and GaN Power Converters

HIGH BANDWIDTH / HIGH CURRENT

- 1 Bandwidth up to 1 GHz for measuring fast rise-times on SiC and GaN FETs
- 2 Complete RF Isolation - Measure tiny changes while rejecting noise from high common mode voltages
- 3 Safety rating to 1000V CAT II



Summary: TICP offers higher bandwidth and lower noise than Clamp-on style and Rogowski probes or differential voltage probes with shunts



High Power Example Uses Cases

TICP100 VS CURRENT TRANSFORMER

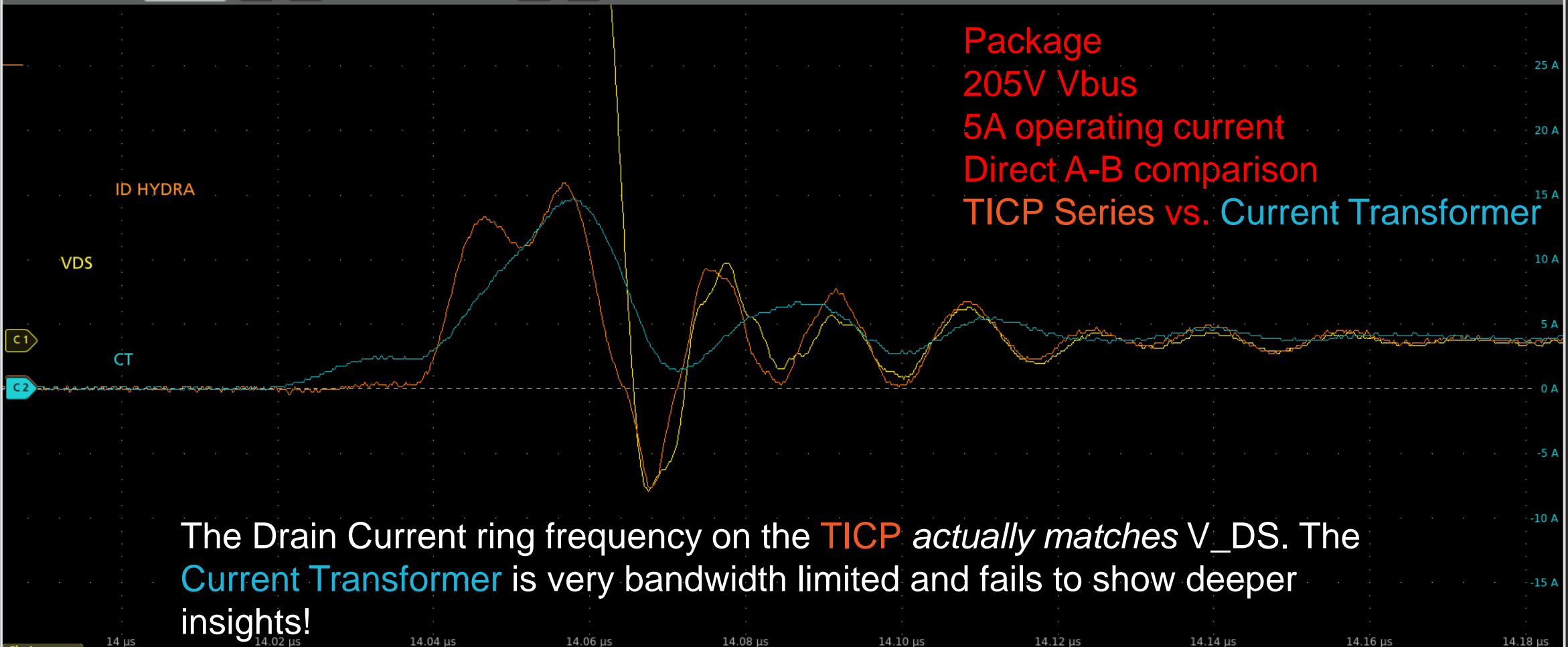
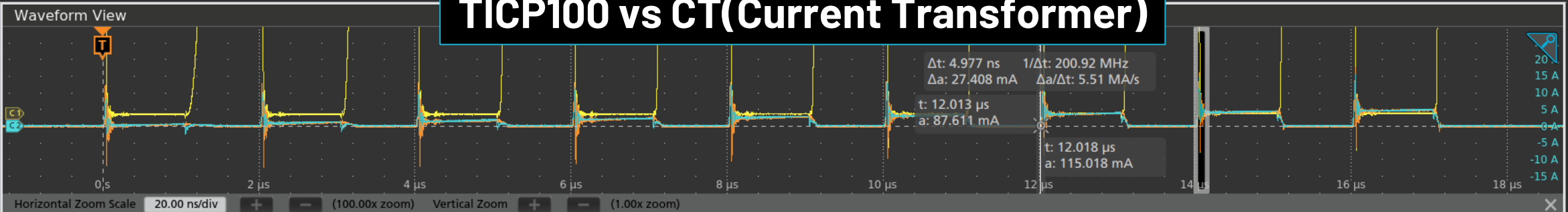


Current Transformer



**Tektronix TICP100
IsoVu Isolated Current Probe**
DC to 1GHz

TICP100 vs CT(Current Transformer)



The Drain Current ring frequency on the **TICP** *actually matches* V_DS. The **Current Transformer** is very bandwidth limited and fails to show deeper insights!

Add New...

Cursors Callout

Measure Search

Results Table Plot

More...

Meas 1 (M1)

Maximum
 μ' : > 52.40 V
 Pos clipping

Meas 2 (1)

Maximum
 μ' : > 52.40 V
 Pos clipping

Meas 3 (6)

Maximum
 μ' : 600.0 mV

Meas 4 (7)

Maximum
 μ' : 400.0 mV

Ch 1 Clipping 10 V/div 1 M Ω DS 500 MHz B_w

Ch 2 5 A/div 1 M Ω 500 MHz B_w

Ch 5 5 A/div 50 Ω 1 GHz

Ch 6 10 V/div 1 M Ω DS 500 MHz B_w

Ch 7 10 V/div 1 M Ω DS 500 MHz B_w

Math 1 1 kA/div Ch1

Horizontal 2 μ s/div 20 μ s SR: 6.25 GS/s 160 ps/pt RL: 125 kpts 6.4%

Trigger 3 1.6 V

Acquisition Auto, Analyze Sample: 8 bits 0 Acqs

Ready 24 Jul 2023 10:40:36 AM

TEKTRONIX CONFIDENTIAL

High Power Example Uses Cases

TICP100 VS TIVP1 VS TCP0150



Tektronix TICP
IsoVu Isolated Current Probe
DC to 1GHz

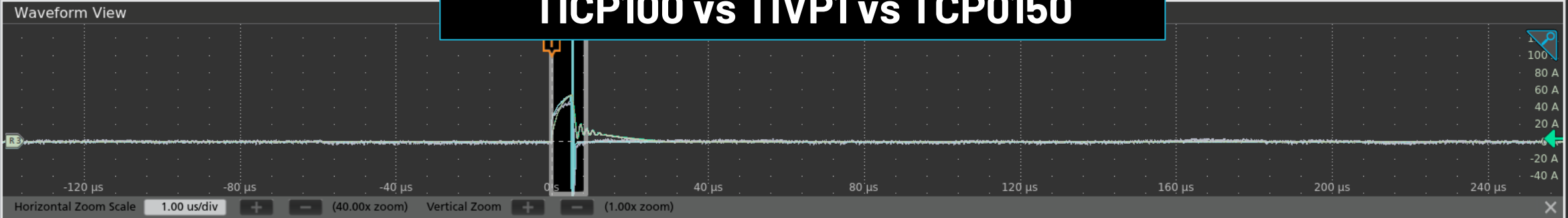


Tektronix TIVP
IsoVu Isolated Voltage Probe
DC to 1GHz



Tektronix TCP0150
AC/DC Current Probe
150 A, DC to 20 MHz

TICP100 vs TIVP1 vs TCP0150



Cursors Callout
Measure Search
Results Table Plot
More...

Meas 1 Mean μ' : 949.2 mV
Meas 2 Maximum μ' : > 139.1 A Pos/Neg clipping
Meas 3 Minimum μ' : > -63.96 A Pos/Neg clipping
Meas 4 Mean μ' : > -1.740 A Pos/Neg clipping

TICP100 shows the real currents that were not seen before

TICP100 shows the ringing and shows the right current levels

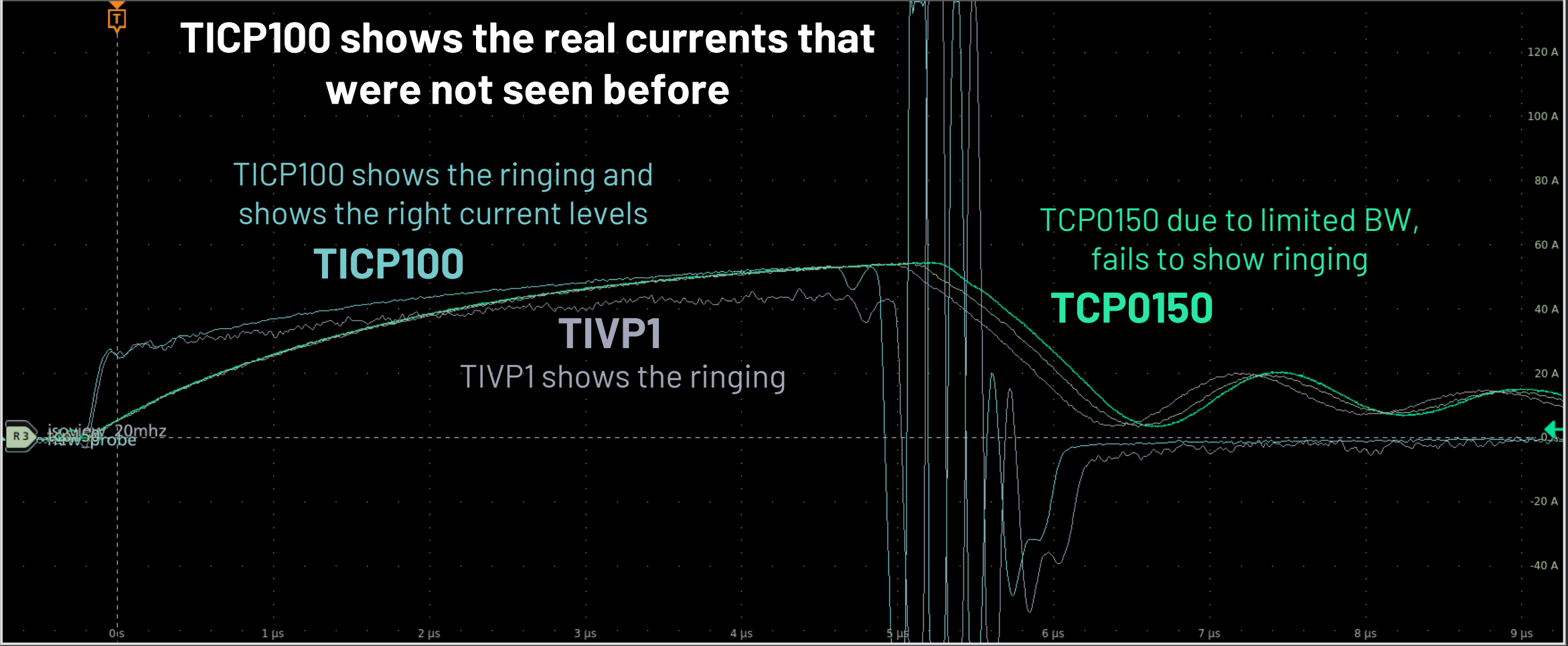
TICP100

TIVP1

TIVP1 shows the ringing

TCP0150 due to limited BW, fails to show ringing

TCP0150



Math 2 20 V/div Ch1 - Ch2
Math 3 20 V/div Ch4 - Ch2
Math 4 20 V/div Ch1 - Ch2
Math 5 500 mV/div Ch6 - Ch2
Ref 1 20 A/div 62.5 MS/s current p...
Ref 2 20 A/div 62.5 MS/s current p...
Bus 1 Parallel
Ref 3 20 A/div 62.5 MS/s ch1_ch8 c...
Ref 4 20 A/div 62.5 MS/s ch1_ch8 c...
Horizontal 40 μs/div 400 μs
SR: 3.125 GS/s 320 ps/pt
RL: 1.25 Mpts 35.2%
Trigger 8 2.4 A
Acquisition Manual, Analyze High Res: 12 bits Single: 0/1
Preview
16 Sep 2024 4:06:11 PM

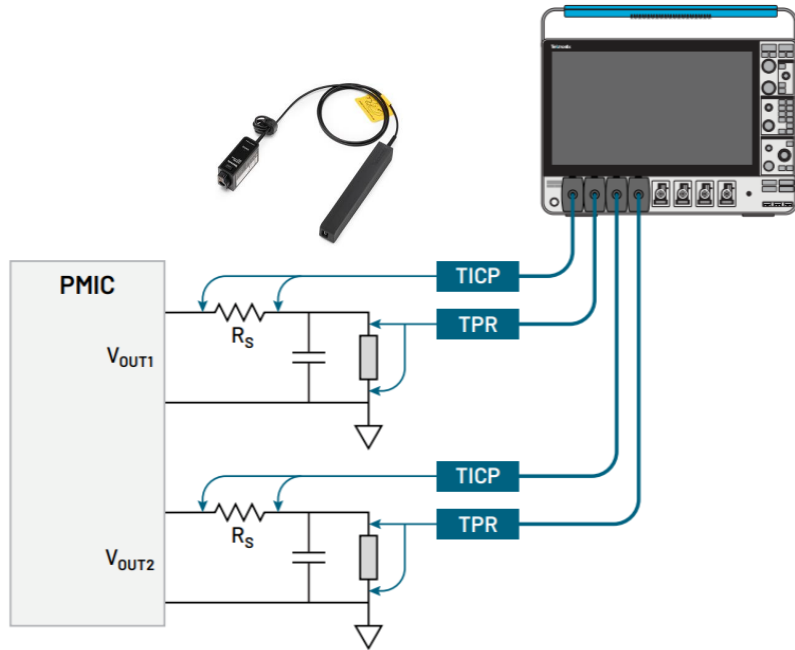
Low Power Example Uses Cases





How does TICP compare to other probes?

LOW-POWER



Market Solutions	TICP + Shunt	Diff probe + shunt	Coaxial Cable + Shunt	SMUs	DMMs	TCPx Current Probes
Bandwidth	High	High	High	Low	Ultra Low	Medium
Isolation	Yes	No	No	No	No	Yes
Intrusive	Yes	Yes	Yes	Yes	Yes	No
Position	Doesn't matter	Doesn't matter	Doesn't matter	Doesn't matter	Doesn't matter	Important
Saturation	No	No	No	No	No	Yes
Probe Tip size	Small	Small	Large	Large	Large	Large
Attenuation	Low	High	Low	Low	Low	N/A

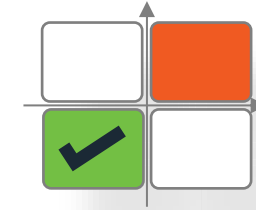


Measuring Microamps in Microseconds

LOW BANDWIDTH / LOW CURRENT

- 1 Capture transient and fast changing currents in embedded systems, as they change state
- 2 1X attenuation and 50Ω input impedance are designed for a low-noise architecture
- 3 Flexible tips help connect to the DUT in tight spaces under challenging test environments

Summary: TICP offers higher accuracy and sensitivity for low-power measurements compared to Clamp-on style probes or using DMMs





Low Power Example Uses Cases

TICP100 VS TCP0030A

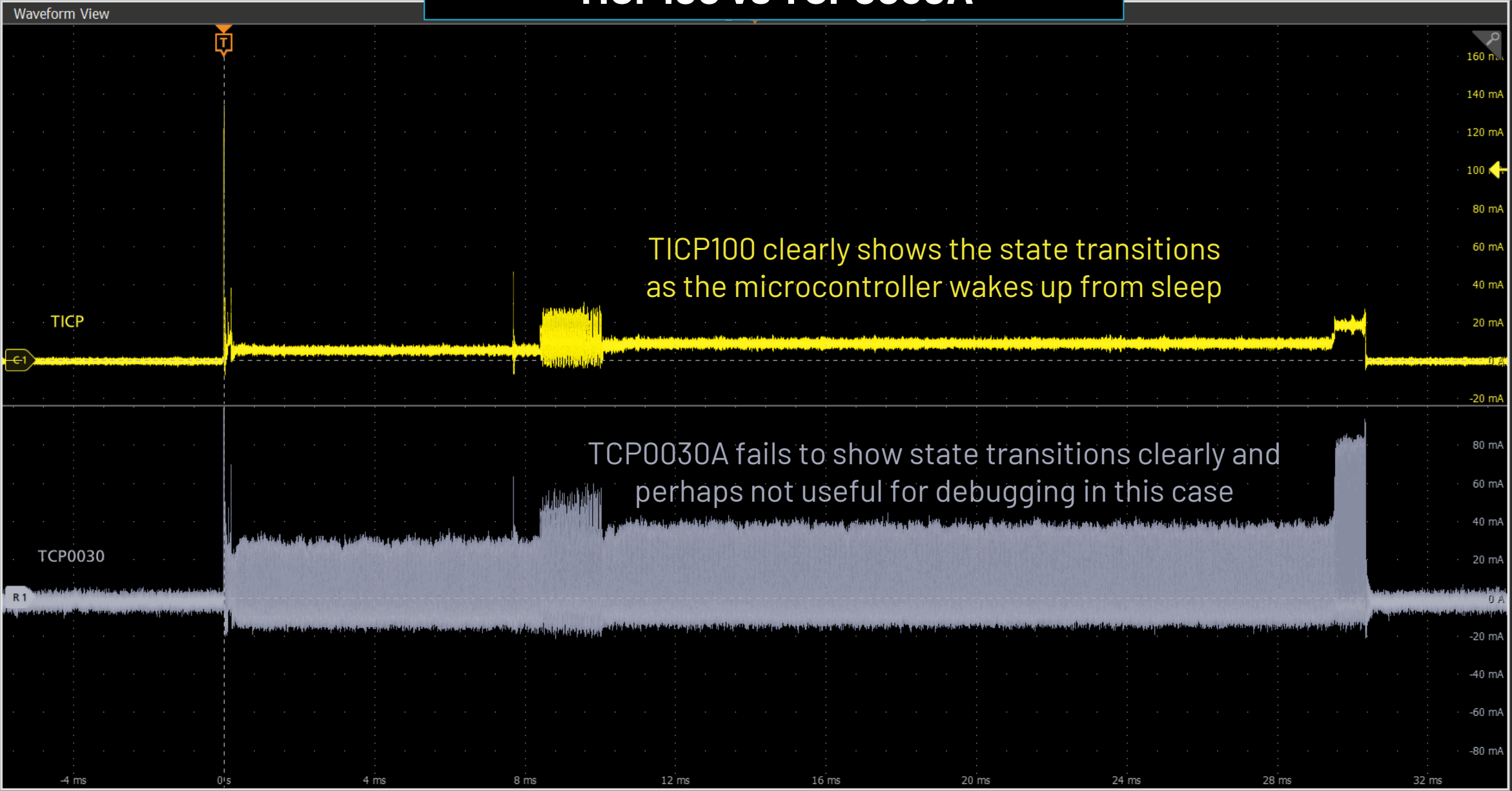


Tektronix TICP
IsoVu Isolated Current Probe
DC to 1GHz



Tektronix TCP0030A
AC/DC Current Probe
30 A, DC to 120 MHz

TICP100 vs TCP0030A



TICP100 clearly shows the state transitions as the microcontroller wakes up from sleep

TCP0030A fails to show state transitions clearly and perhaps not useful for debugging in this case

Add New...

- Cursors
- Callout
- Measure
- Search
- Results Table
- Plot
- More...

Ch 1
20 mA/div
50 Ω
1 THz

Ref 1
20 mA/div
12.5 MS/s
TCP_lowC...

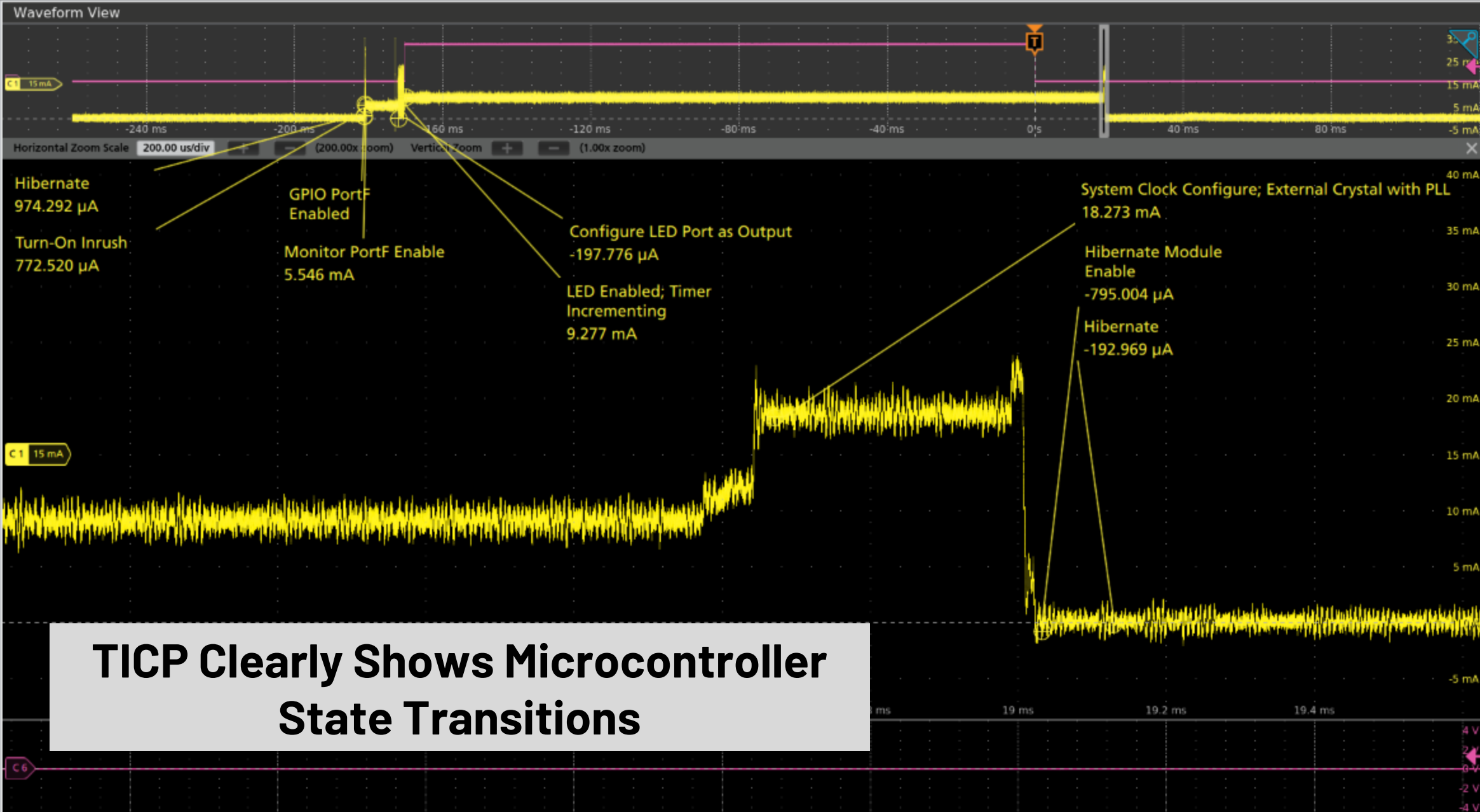
Add New Math Add New Ref Add New Bus Add New Scope

Horizontal 4 ms/div

Acquisition Single

Offline

07 Nov 2024 5:02:29 PM



TICP Clearly Shows Microcontroller State Transitions

Add New...

Cursors Callout

Measure Search

Results Table Plot

More...

Ch 1 5 mA/div 50 Ω 200 MHz BW

Ch 6 1 V/div 1 M Ω DS 500 MHz BW

2 3 4 5 7 8

Add New Math Add New Ref Add New Bus

DVM AFG

Horizontal 40 ms/div 400 ms

SR: 1.25 GS/s 800 ps/pt

RL: 500 Mpts 69.7%

Trigger 6 1.28 V

Acquisition Manual, Analyze

High Res: 15 bits

Single: 0/1

Preview

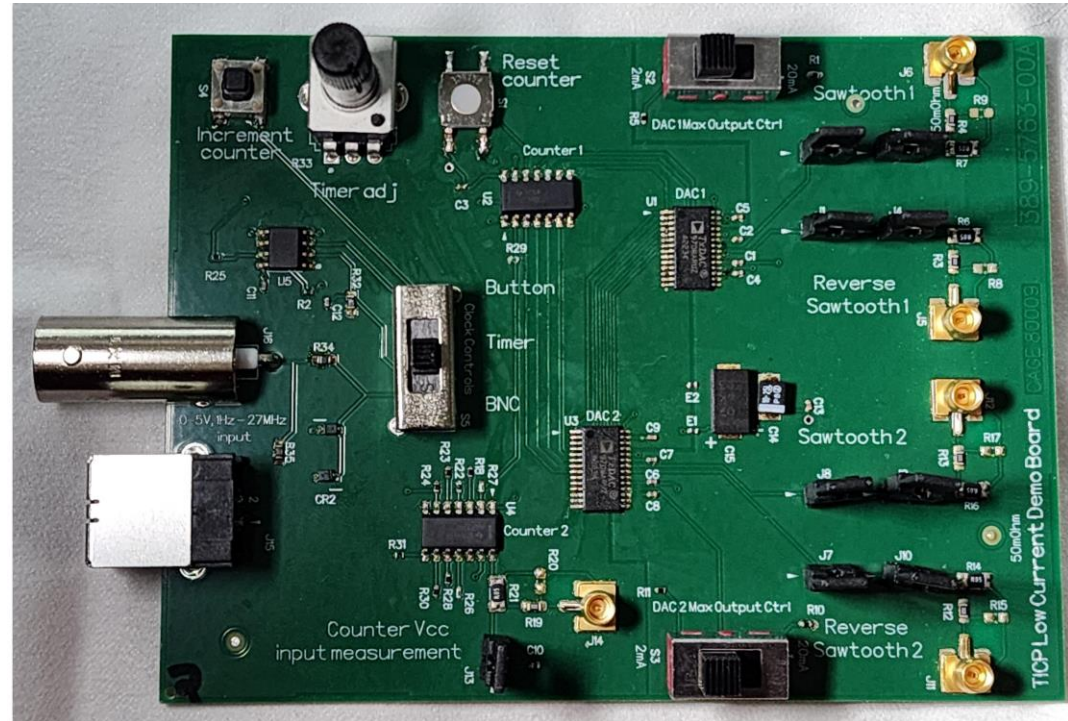
DAC output current

TICP100 vs TCP0030A

DAC Steps = 255

Current Range 0-20 mA

Current per step change = $20/255 = 78 \mu\text{A}$



Low Power Example Uses Cases

TICP100 VS TCP0030A

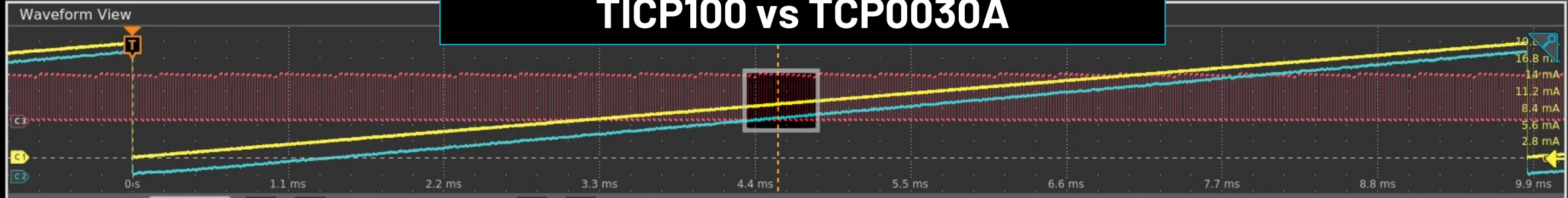


Tektronix TICP
IsoVu Isolated Current Probe
DC to 1GHz

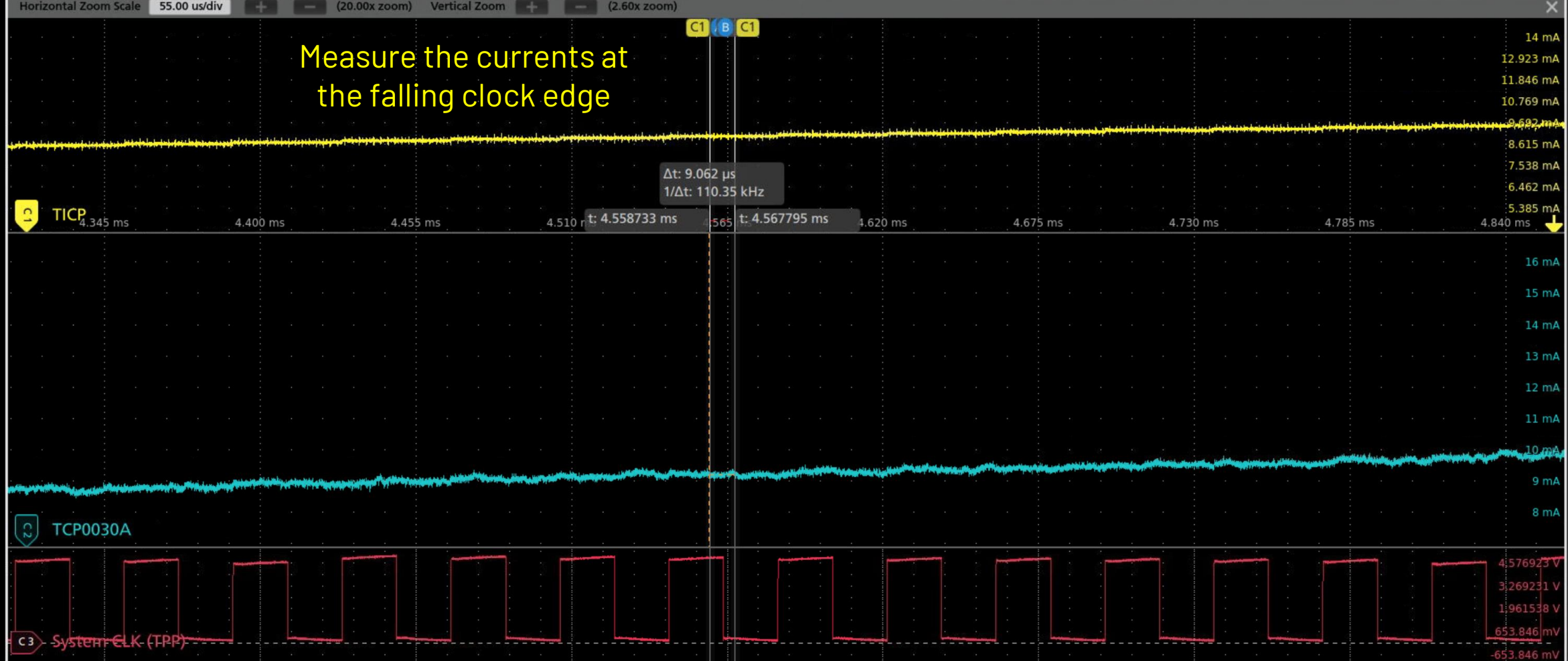


Tektronix TCP0030A
AC/DC Current Probe
30 A, DC to 120 MHz

TICP100 vs TCP0030A



Measure the currents at the falling clock edge



Ch 1	Ch 2	Ch 3
2.8 mA/div	2.6 mA/div	1.7 V/div
50 Ω	1 M Ω	1 GHz
20 MHz B_w	20 MHz B_w	1 GHz B_w

4 Add New Math Add New Ref Add New Bus DVM AFG

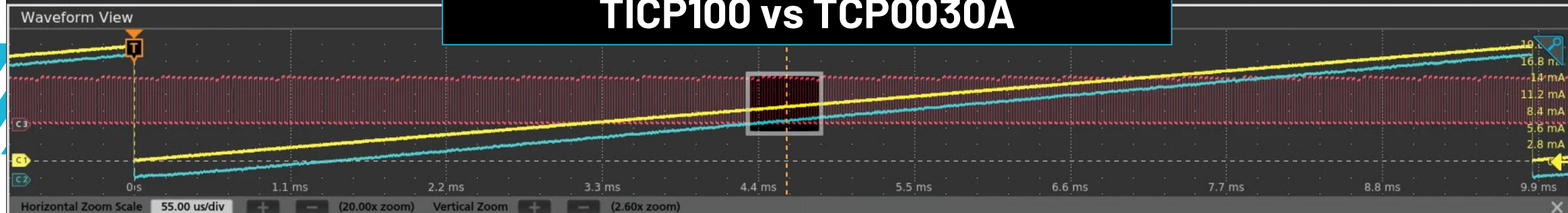
Horizontal: 1.1 ms/div 11 ms SR: 62.5 MS/s 16 ns/pt RL: 687.5 kpts 8%

Trigger: 1 \sim -224 μ A

Acquisition: Auto, Analyze Sample: 12 bits Single: 0/1

Preview 08 Nov 2024 11:27:35 AM

TICP100 vs TCP0030A



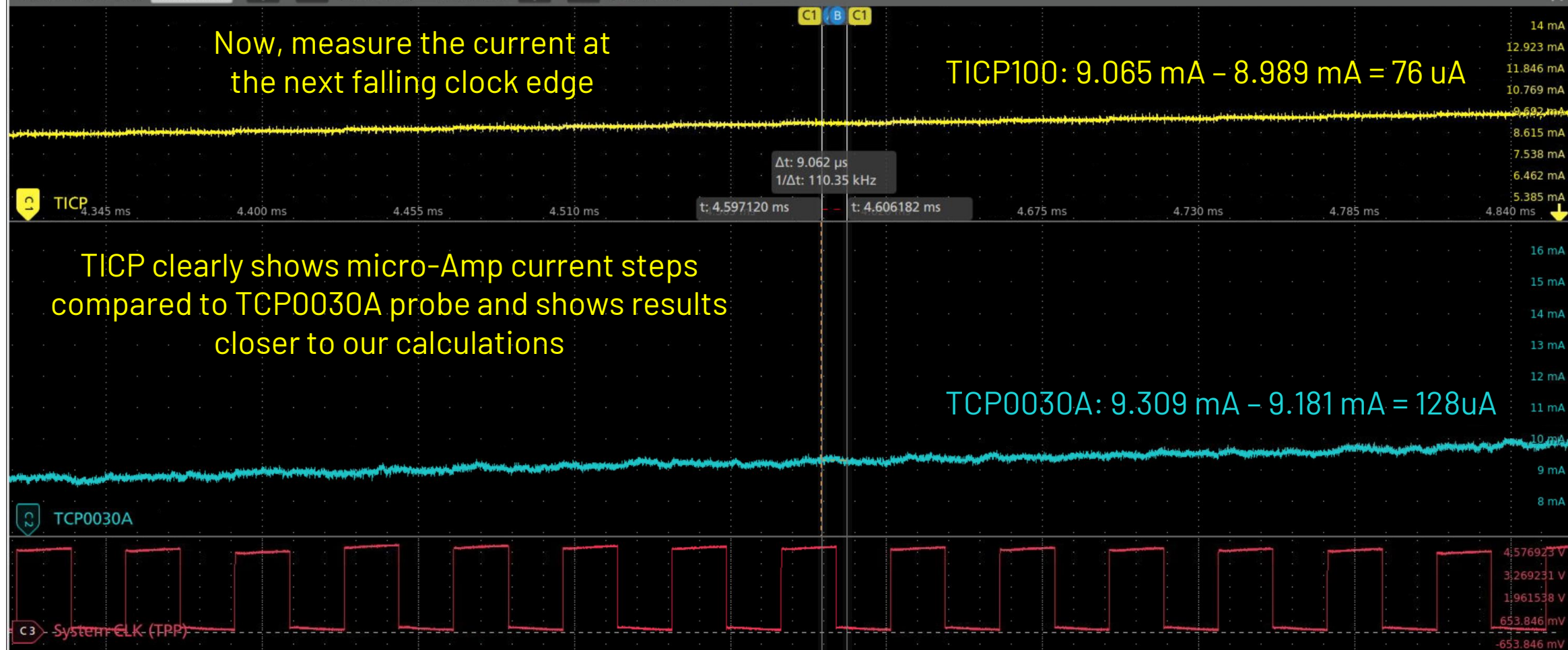
Now, measure the current at the next falling clock edge

$$\text{TICP100: } 9.065 \text{ mA} - 8.989 \text{ mA} = 76 \text{ }\mu\text{A}$$

$\Delta t: 9.062 \text{ }\mu\text{s}$
 $1/\Delta t: 110.35 \text{ kHz}$

TICP clearly shows micro-Amp current steps compared to TCP0030A probe and shows results closer to our calculations

$$\text{TCP0030A: } 9.309 \text{ mA} - 9.181 \text{ mA} = 128 \text{ }\mu\text{A}$$



Ch 1	Ch 2	Ch 3
2.8 mA/div	2.6 mA/div	1.7 V/div
50 Ω	1 M Ω	1 GHz
20 MHz Bw	20 MHz Bw	1 GHz Bw

4 Add New Math Add New Ref Add New Bus DVM AFG

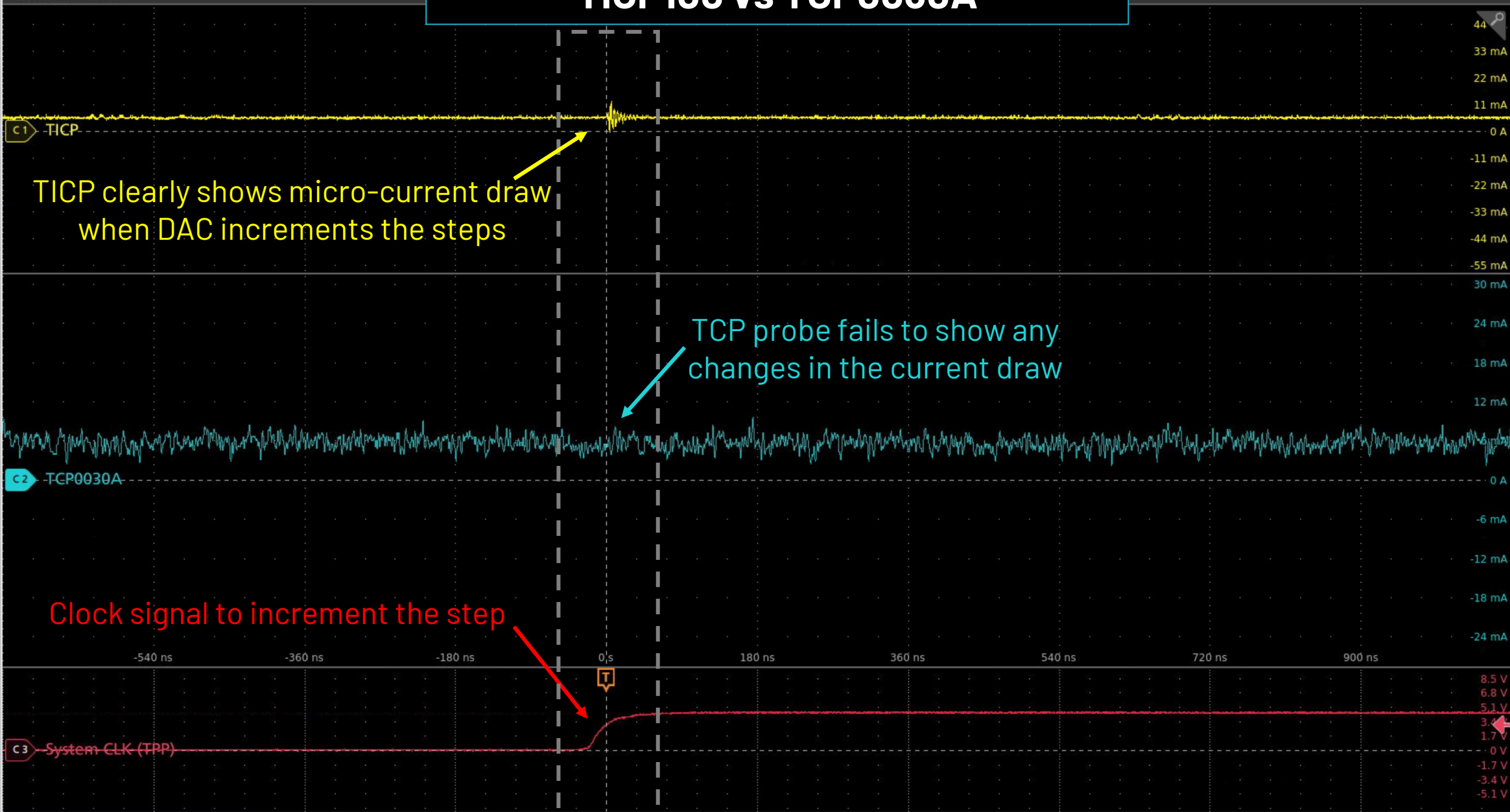
Horizontal: 1.1 ms/div 11 ms SR: 62.5 MS/s 16 ns/pt RL: 687.5 kpts 8%

Trigger: 1 -224 μA

Acquisition: Auto, Analyze Sample: 12 bits Single: 0/1

Preview 08 Nov 2024 11:28:06 AM

TICP100 vs TCP0030A



TICP clearly shows micro-current draw when DAC increments the steps

TCP probe fails to show any changes in the current draw

Clock signal to increment the step

Add New...

Cursors Callout

Measure Search

Results Table Plot

More...

Meas 1 1

Mean

μ': 5.503 mA

Meas 2 2

Mean

μ': 5.665 mA

Meas 3 3

Frequency

μ': --

Too few edges

Ch 1	Ch 2	Ch 3
11 mA/div	6 mA/div	1.7 V/div
50 Ω	1 MΩ	1 GHz
1 GHz	120 MHz	1 GHz

4

Add New Math Add New Ref Add New Bus

DVM AFG

Horizontal
 180 ns/div 1.8 μs
 SR: 6.25 GS/s 160 ps/pt
 RL: 11.25 kpts 40%

Trigger
3 2.99 V

Acquisition
 Auto, Analyze
 Sample: 8 bits
 Single: 1/1

Stopped

08 Nov 2024 11:50:30 AM



TICP Series IsoVu™ Isolated Current Probes

INDUSTRY FIRST RF ISOLATED CURRENT PROBES



Bandwidth	250 MHz, 500 MHz, 1 GHz
DC Gain Accuracy	± 1.5%
Isolation	RF Isolation scheme
Common Mode Rejection Ratio (CMRR)	140 dB at DC Up to 90 dB at 1 MHz
Common Mode Voltage	1800 V; For use in a Pollution degree 1 environment 1300 V; Pollution degree 2 1000 V CAT II; 600V CAT III
RMS Input Referred Noise	4.7 nV/RT Hz (<150 µV at 1 GHz, <21 µV at 20 MHz)
Current Measurements	AC + DC
Compatible Oscilloscopes	4 Series MSO, 5 Series MSO, 6 Series MSO, 4 Series B MSO, 5 Series B MSO, 6 Series B MSO, 5 Series MSO LP



**THANK
YOU**

